

L Number	Hits	Search Text	DB	Time stamp
1	1	5854135.pn.	USPAT; EPO; JPO; IBM_TDB	2004/02/06 08:16
2	0	(contact or via) same (dielectric or insulating) same endpoint same bias same voltage	USPAT; EPO; JPO; IBM_TDB	2004/02/06 08:18
3	303	(contact or via) and (dielectric or insulating) and endpoint and bias and voltage	USPAT; EPO; JPO; IBM_TDB	2004/02/06 09:43
4	1		USPAT	2004/02/06 09:32
5	1		USPAT	2004/02/06 09:32
6	14	(SAC or "self aligned contact") same endpoint	USPAT; EPO; JPO; IBM_TDB	2004/02/06 09:39
7	297	(SAC or "self aligned contact") and endpoint	USPAT; EPO; JPO; IBM_TDB	2004/02/06 09:39
8	54	(SAC or "self aligned contact") and endpoint and bias	USPAT; EPO; JPO; IBM_TDB	2004/02/06 09:39
9	301	(contact or opening) and via and (dielectric or insulating) and endpoint and bias	USPAT; EPO; JPO; IBM_TDB	2004/02/06 10:20
10	217	(contact or opening) and via and gate and spacer and endpoint	USPAT; EPO; JPO; IBM_TDB	2004/02/06 10:20
11	23	(SAC or "self aligned contact") and endpoint and etch\$3 and bias	USPAT; EPO; JPO; IBM_TDB	2004/02/06 10:45
12	11	bias same compensation same (voltage or volts) same etch\$3	USPAT; EPO; JPO; IBM_TDB	2004/02/06 10:46